

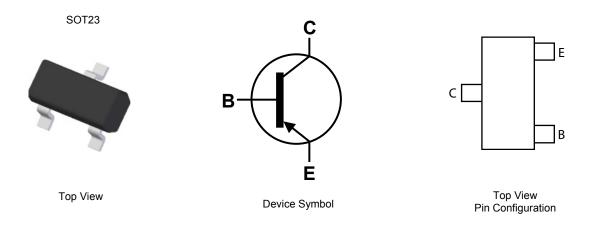
## **45V PNP MEDIUM POWER TRANSISTOR IN SOT23**

## **Features**

- BV<sub>CEO</sub> > -45V
- I<sub>C</sub> = -800mA high Continuous Collector Current
- Low Saturation Voltage V<sub>CE(sat)</sub> < -300mV @ 100mA</li>
- Complementary NPN Type: BCW66H
- Totally Lead-Free & Fully RoHS compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

## **Mechanical Data**

- Case: SOT23
- Case Material: molded plastic, "Green" molding compound
- UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminals: Finish Matte Tin Plated Leads, Solderable per MIL-STD-202, Method 208 63
- Weight 0.008 grams (approximate)



## **Ordering Information (Note 4)**

Part Number	Marking	Reel size (inches)	Tape width (mm)	Quantity per reel
BCW68HTA	DH	7	8	3,000

Notes:

- 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.
- 2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com.

## **Marking Information**





**Maximum Ratings** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

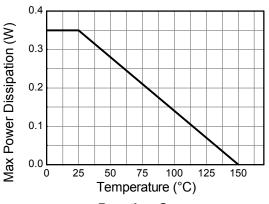
Characteristic	Symbol	Value	Unit
Collector-Base Voltage	V <sub>CES</sub>	-60	V
Collector-Emitter Voltage	V <sub>CEO</sub>	-45	V
Emitter-Base Voltage	V <sub>EBO</sub>	-7	V
Continuous Collector Current	Ic	-800	mA
Peak Pulse Current	I <sub>CM</sub>	-1000	mA
Base Current	I <sub>B</sub>	-100	mA

# Thermal Characteristics (@TA = +25°C, unless otherwise specified.)

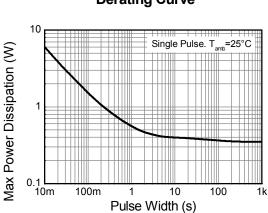
Characteristic		Symbol	Value	Unit	
Power Dissipation	(Note 5)	_	310	mW	
Fower Dissipation	(Note 6)	P <sub>D</sub>	350	IIIVV	
Thermal Posistance, Junction to Ambient	(Note 5)	D	403	°C/W	
Thermal Resistance, Junction to Ambient	(Note 6)	R <sub>0JA</sub>	R <sub>0JA</sub> 357		
Thermal Resistance, Junction to Leads	(Note 7)	R <sub>0JL</sub>	350	°C/W	
Operating and Storage Temperature Range	$T_{J_1}T_{STG}$	-55 to +150	°C		

Notes:

- 5. For the device mounted on minimum recommended pad layout FR4 PCB with high coverage of single sided 1oz copper in still air condition; the device is measured when operating in a steady-state condition.
- 6. Same as note (5), except the device is mounted on 15mm x 15mm FR4 PCB.
- 7. Thermal resistance from junction to solder-point (at the end of the leads).







**Pulse Power Dissipation** 

350 350 300 250 D=0.5 150 D=0.1 D=0.05 100μ 1m 10m 10m 1 10 100 1k Pulse Width (s)

**Transient Thermal Impedance** 





# Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)

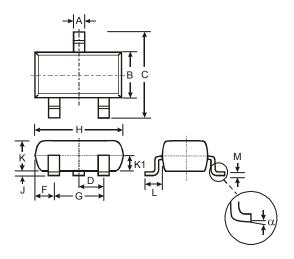
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
OFF CHARACTERISTICS						
Collector-Base Breakdown Voltage	BV <sub>CES</sub>	-60	_	_	V	$I_{C} = -10\mu A$
Collector-Emitter Breakdown Voltage (base open) (Note 8)	BV <sub>CEO</sub>	-45	_	_	V	I <sub>CEO</sub> = -10mA
Emitter-Base Breakdown Voltage	$BV_{EBO}$	-7	_	_	V	$I_{EBO} = -10\mu A$
Collector-emitter cut-off current	I <sub>CES</sub>	_	<1 —	-20 -10	nΑ μΑ	V <sub>CES</sub> = -45V V <sub>CES</sub> = -45V, T <sub>A</sub> = +150°C
Emitter-base Cut-off Current	I <sub>EBO</sub>	_	<1	-20	nA	V <sub>EBO</sub> = -5.6V
ON CHARACTERISTICS (Note 8)						
Static Forward Current Transfer Ratio	h <sub>FE</sub>	250 100	350 —	630 —	_	I <sub>C</sub> = -100mA, V <sub>CE</sub> = -1V I <sub>C</sub> = -500mA, V <sub>CE</sub> = -2V
Collector-Emitter Saturation Voltage	V <sub>CE(sat)</sub>	_	 -700	-300 —	mV	I <sub>C</sub> = -100mA, I <sub>B</sub> = -10mA I <sub>C</sub> = -500mA, I <sub>B</sub> = -50mA
Base-Emitter Saturation Voltage	V <sub>BE(sat)</sub>	_	_	-2	V	$I_C = -500 \text{mA}, I_B = -50 \text{mA}$
SMALL SIGNAL CHARACTERISTICS (Note 8)						
Transition Frequency	f⊤	100	_	_	MHz	$I_C = -20$ mA, $V_{CE} = -10$ V, $f = 100$ MHz
Output Capacitance	$C_obo$	_	12	18	pF	$V_{CB}$ = -10V, f = 1MHz
Input Capacitance	C <sub>ibo</sub>	_	_	80	pF	$V_{CB} = -0.5V, f = 1MHz$
Noise Figure	N	_	2	10	dB	$\begin{split} &I_C = \text{-0.2mA. V}_{CE} = \text{-5V}, \\ &R_G = \text{1K}\Omega, \text{f} = \text{1KHz}, \\ &\Delta \text{f} = \text{200Hz} \end{split}$
Turn-On Time	t <sub>on</sub>	_	_	100	ns	I <sub>C</sub> = -150mA.
Turn-Off Time	t <sub>off</sub>	_	_	400	ns	$I_{B1} = -I_{B2} = -15\text{mA}$ $R_L = 150\Omega$

Notes: 8. Measured under pulsed conditions. Pulse width  $\leq$  300 $\mu$ s. Duty cycle  $\leq$  2%.



# **Package Outline Dimensions**

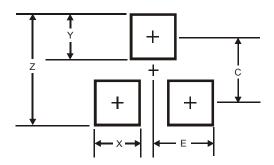
Please see AP02002 at http://www.diodes.com/datasheets/ap02002.pdf for latest version.



SOT23					
Dim	Min	Max	Тур		
Α	0.37	0.51	0.40		
В	1.20	1.40	1.30		
С	2.30	2.50	2.40		
D	0.89	1.03	0.915		
F	0.45	0.60	0.535		
G	1.78	2.05	1.83		
Н	2.80	3.00	2.90		
7	0.013	0.10	0.05		
K	0.903	1.10	1.00		
K1	-	-	0.400		
١	0.45	0.61	0.55		
М	0.085	0.18	0.11		
α	0°	8°	-		
All Dimensions in mm					

# **Suggested Pad Layout**

Please see AP02001 at http://www.diodes.com/datasheets/ap02001.pdf for the latest version.



Dimensions	Value (in mm)
Z	2.9
X	0.8
Υ	0.9
С	2.0
Е	1.35





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